



DOCKET NO: 252311US2S

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

:

SYOTARO ONO, ET AL.

: EXAMINER: DICKEY, T.

SERIAL NO: 10/829,173

:

FILED: APRIL 22, 2004

: GROUP ART UNIT: 2826

FOR: SEMICONDUCTOR DEVICE  
HAVING VERTICAL MOS GATE  
STRUCTURE AND METHOD OF  
MANUFACTURING THE SAME

:

**AMENDMENT FILED CONCURRENTLY WITH**  
**REQUEST FOR CONTINUED EXAMINATION (RCE)**

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated January 12, 2006, please amend the  
above-identified application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page  
3 of this paper.

**Remarks** begin on page 7 of this paper.